

BTS612N1

Data Sheet

<u>RFO</u>

Power Switch Hi Side 1.8A

Manufacturers	Infineon Technologies Corporation	
Package/Case	TO-220	
Product Type	High-side / low-side switch, the driver, the receiver	
RoHS		Images are for reference only
Lifecycle		

General Description

BTS612N1 is a type of Power Switch IC (Integrated Circuit) manufactured by Infineon Technologies.

Please submit RFQ for BTS612N1 or Email to us: sales@ovaga.com We will contact you in 12 hours.

Features	Application
It is a high-side power switch with an integrated vertical power MOSFET	BTS612N1 is commonly used in automotive and industrial applications to control the power supply to various loads such as motors, solenoids, and other devices that require high-current switching.
It has a built-in protection against overcurrent, overvoltage, and overtemperature	It can also be used in other applications where high-side switching is required, such as in lighting control, power distribution systems, and battery management systems.
The device can handle a maximum load current of 3A	
It has a low on-resistance of $75 \mathrm{m}\Omega$	

(milliohms) at 25°C.



Related Products



BTS442E2E3062A

Infineon Technologies Corporation PG-TO263-5



BTS555E3146

Infineon Technologies Corporation TO-218-5



BTS611L1E3128A

BTS432E2E3062A

Infineon Technologies Corporation P-TO220-7

Infineon Technologies Corporation



BTS412B2

Infineon Technologies Corporation TO-220-5

BTS550P

Infineon Technologies Corporation TO-3P-5

BTS621L1E3128A

Infineon Technologies Corporation TO-263-7



BTS432D2

TO-263

Infineon Technologies Corporation TO-263

